NSN 5961-01-645-8579

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-645-8579 **Overall Height:** 1.09 inches **Overall Width:** 2.9 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1800.0 nonrepetitive peak reverse voltage **Current Rating Per Characteristic:** 2350.0 amperes on-state current, rms total **Power Rating Per Characteristic:** 200.0 watts peak gate power dissipation **Product Name:** Rectifier **Special Features:** Phase control; operating temperature: -40 to +125 degrees c Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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